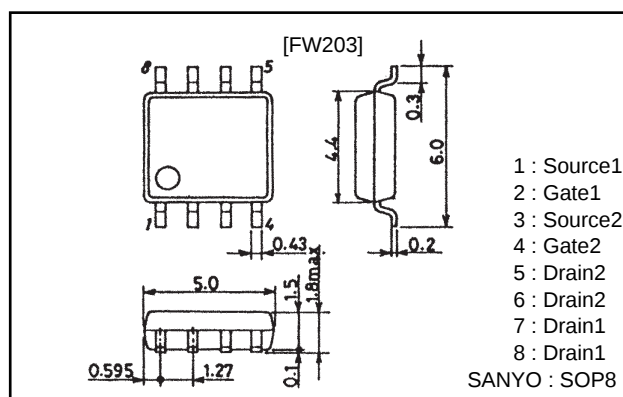


SANYO**Ultrahigh-Speed Switching Applications****Features**

- Low ON resistance
- Ultrahigh-speed switching.
- Composite type with two 4V-drive N-channel MOSFETs facilitating high-density mounting.
- Matched pair capability.

Package Dimensions

unit: mm

2129-SOP8**Specifications****Absolute Maximum Ratings** at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V_{DSS}		30	V
Gate-to-Source Voltage	V_{GSS}		± 20	V
Drain Current (DC)	I_D		5	A
Drain Current (pulse)	I_{DP}	$PW \leq 10\mu s$, duty cycle $\leq 1\%$	48	A
Allowable Power Dissipation	P_D	Mounted on a ceramic board (1000mm ² ×0.8mm) 1unit	1.7	W
Total Dissipation	P_T	Mounted on a ceramic board (1000mm ² ×0.8mm)	2.0	W
Channel Temperature	T_{ch}		150	°C
Storage temperature	T_{stg}		-55 to +150	°C

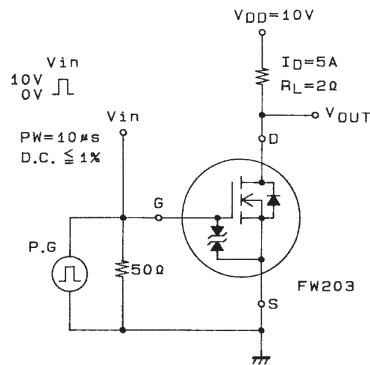
Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
D-S Breakdown Voltage	$V_{(BR)DSS}$	$I_D=1mA$, $V_{GS}=0$	30			V
Zero-Gate-Voltage Drain Current	I_{DSS}	$V_{DS}=30V$, $V_{GS}=0$			100	μA
Gate-to-Source Leakage Current	I_{GSS}	$V_{GS}=\pm 16V$, $V_{DS}=0$			± 10	μA
Cutoff Voltage	$V_{GS(off)}$	$V_{DS}=10V$, $I_D=1mA$	1.0		2.5	V
Forward Transfer Admittance	$ y_{fs} $	$V_{DS}=10V$, $I_D=5A$	5	8		S
Static Drain-to-Source ON-State Resistance	$R_{DS(on)}$	$I_D=5A$, $V_{GS}=10V$		36	46	m Ω
	$R_{DS(on)}$	$I_D=5A$, $V_{GS}=4V$		58	78	m Ω
Input Capacitance	C_{iss}	$V_{DS}=10V$, $f=1MHz$		550		pF
Output Capacitance	C_{oss}	$V_{DS}=10V$, $f=1MHz$		330		pF
Reverse Transfer Capacitance	C_{rss}	$V_{DS}=10V$, $f=1MHz$		120		pF

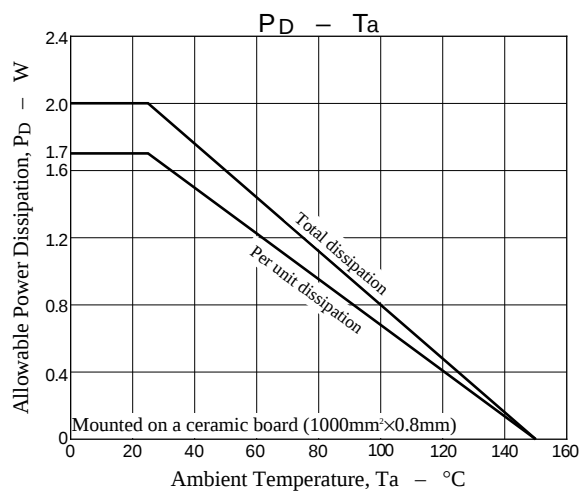
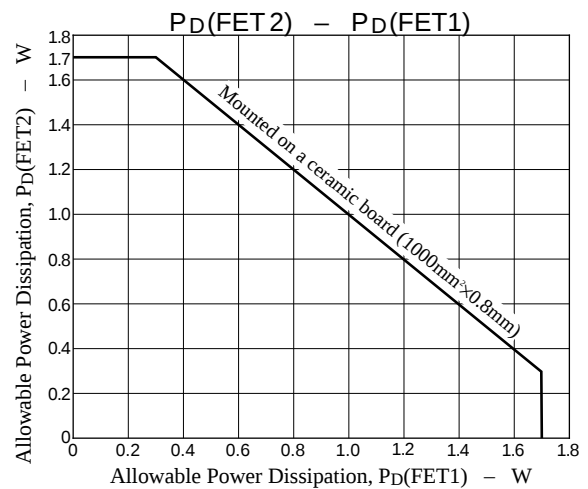
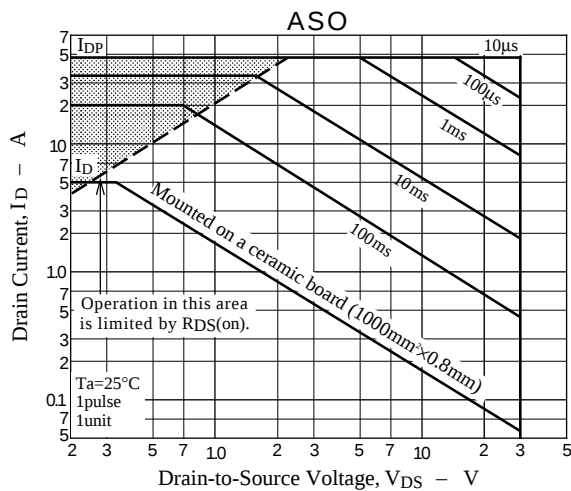
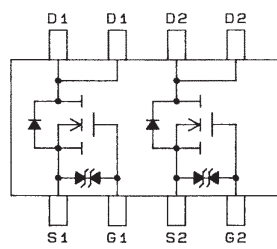
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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Turn-ON Delay Time	$t_{d(on)}$	See specified Test Circuit.		15		ns
Rise Time	t_r	"		200		ns
Turn-OFF Delay Time	$t_{d(off)}$	"		150		ns
Fall Time	t_f	"		160		ns
Diode Forward Voltage	V_{SD}	$I_S=5A, V_{GS}=0$		1.0	1.2	V

Switching Time Test Circuit**Electrical Connection**

(Top view)



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